

## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ι <sub>C</sub>	1	А
Peak Pulse Collector Current	ICM	1.5	A
Base Current	Ι <sub>Β</sub>	300	mA
Peak Base Current	I <sub>BM</sub>	1	A

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Notes 5 & 7)		405	
	(Notes 5 & 8)	D	510	m)\/
	(Notes 6 & 7)	PD	1650	mW
	(Notes 6 & 8)		2470	
Thermal Resistance, Junction to Ambient	(Notes 5 & 7)		308	
	(Notes 5 & 8)	D	245	°C/W
	(Notes 6 & 7)	R <sub>0JA</sub>	76	·C/w
	(Notes 6 & 8)		51	
Thermal Resistance, Junction to Lead	(Note 9)	R <sub>θJL</sub>	18	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

### ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the exposed collector pads on minimum recommended pad layout that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note (5), except the device is mounted with the collector pad on 28mm x 28mm (8cm<sup>2</sup>) 2oz copper.

7. For a dual device with one active die.

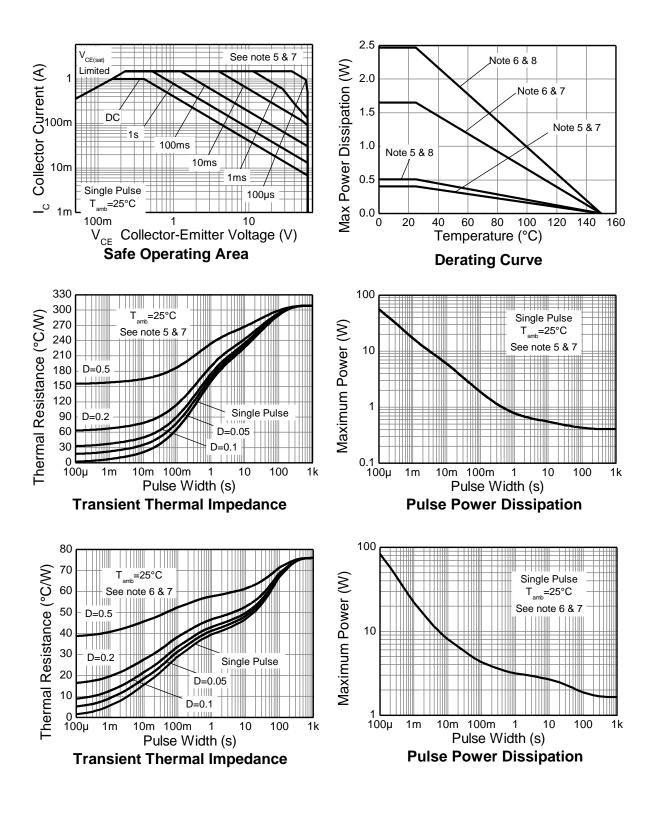
8. For dual device with 2 active die running at equal power.

9. Thermal resistance from junction to solder-point (on the exposed collector pads).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**



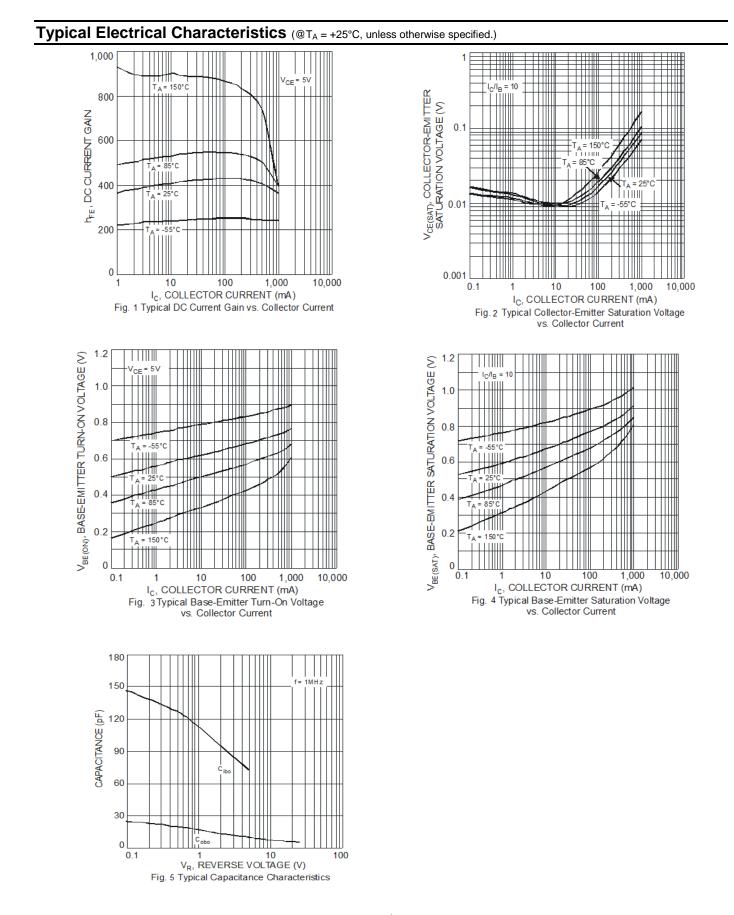


# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60	_		V	$I_{\rm C} = 100 \mu {\rm A}$
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	60		—	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BVEBO	7			V	I <sub>E</sub> = 100μA
Collector-Base Cutoff Current				100	nA	$V_{CB} = 48V, I_E = 0$
	I <sub>CBO</sub>	_	_	50	μA	V <sub>CB</sub> = 48V, I <sub>E</sub> = 0, T <sub>A</sub> = +150°C
Emitter-Base Cutoff Current	I <sub>EBO</sub>	_	_	100	nA	$V_{EB} = 5.6V, I_{C} = 0$
DC Current Gain (Note 11)		290	430			$V_{CE} = 2V, I_{C} = 100mA$
	h <sub>FE</sub>	150	220			$V_{CE} = 2V, I_{C} = 500mA$
		70	110	_		$V_{CE} = 2V, I_C = 1A$
Collector-Emitter Saturation Voltage (Note 11)		_	90	120		$I_{C} = 500 \text{mA}, I_{B} = 50 \text{mA}$
	V <sub>CE(SAT)</sub>		170	220	mV	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
			185	240		I <sub>C</sub> = 1A, I <sub>B</sub> = 50mA
Equivalent On-Resistance (Note 11)	R <sub>CE</sub> (SAT)	_	180	240	mΩ	$I_{C} = 500 \text{mA}, I_{B} = 50 \text{mA}$
	V <sub>BE(SAT)</sub>	_	_	1	V	$I_{\rm C} = 0.5 \text{A}, I_{\rm B} = 50 \text{mA}$
Base-Emitter Saturation Voltage (Note 11)		_		1.1		$I_{\rm C} = 1$ A, $I_{\rm B} = 50$ mA
		_	_	1.1		I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Base-Emitter Turn-on Voltage (Note 11)	V <sub>BE(ON)</sub>			0.9	V	$V_{CE} = 2V, I_{C} = 0.5A$
Transition Frequency	f <sub>T</sub>	90	175	_	MHz	$V_{CE} = 10V, I_C = 50mA,$ f = 100MHz
Output (Collector) Capacitance	C <sub>OB(C)</sub>	_	4	6	pF	V <sub>CB</sub> = -10V, f = 1MHz
Turn-On Time	t <sub>ON</sub>	_	105		ns	
Delay Time	t <sub>D</sub>	_	15		ns	
Rise Time	t <sub>R</sub>	_	90	_	ns	$V_{\rm CC} = -10V, I_{\rm C} = -0.5A,$
Turn-Off Time	t <sub>OFF</sub>	_	540		ns	$I_{B1} = -I_{B2} = 25 \text{mA}$
Storage Time	ts		410		ns	
Fall Time	tF		130		ns	

Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu s. Duty cycle <math display="inline">{\leq}2\%.$ 

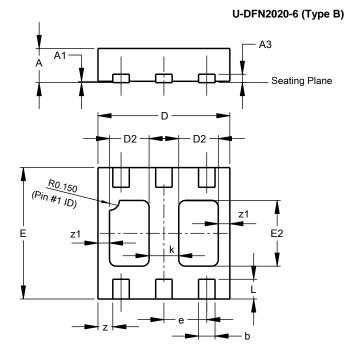






## **Package Outline Dimensions**

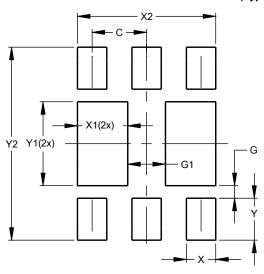
Please see http://www.diodes.com/package-outlines.html for the latest version.



	U-DFN2020-6 Type B				
Dim	Min	Max	Тур		
Α	0.545	0.605	0.575		
A1	0.00	0.05	0.02		
A3	_	_	0.13		
b	0.20	0.30	0.25		
D	1.95	2.075	2.00		
D2	0.50	0.70	0.60		
е	-	-	0.65		
E	1.95	2.075	2.00		
E2	0.90	1.10	1.00		
k	_	_	0.45		
L	0.25	0.35	0.30		
z	_	_	0.225		
z1	_	_	0.175		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



# U-DFN2020-6 (Type B)

Dimensions	Value
Dimensions	(in mm)
С	0.650
G	0.150
G1	0.450
Х	0.350
X1	0.600
X2	1.650
Ý	0.500
Y1	1.000
Y2	2.300



### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2016, Diodes Incorporated

#### www.diodes.com